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FLUORIDE ADJ DOP\$4

**Term:**

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<u>DB Name</u>	<u>Query</u>	<u>Hit Count</u>	<u>Set Name</u>
JPAB,EPAB,DWPI	FLUORIDE ADJ DOP\$4	90	<u>L8</u>
TDBD	FLUORIDE ADJ DOP\$4	0	<u>L7</u>
TDBD	HALIDE ADJ DOP\$4	0	<u>L6</u>
JPAB,EPAB,DWPI	HALIDE ADJ DOP\$4	65	<u>L5</u>
EPAB	HALIDE ADJ DOP\$4	13	<u>L4</u>
JPAB	HALIDE ADJ DOP\$4	14	<u>L3</u>
JPAB	FLUORIDE ADJ DOP\$4	9	<u>L2</u>
JPAB	FLUORIDE DOP\$4	37985	<u>L1</u>

=> ACT LDIELECT/A

L1 ( 485382)SEA FILE=USPAT TRENCH ISOLATION OR GROOVE? OR CAVITY?  
L2 ( 3553)SEA FILE=USPAT LOW DIELECTRIC CONSTANT  
L3 631 SEA FILE=USPAT L1 AND L2

=> ACT LDIELECT1/A

L4 ( 555)SEA FILE=USPAT DOP? SILICON DIOXIDE?  
L5 ( 424320)SEA FILE=USPAT TRENCH OR GROOVE OR CAVITY  
L6 122 SEA FILE=USPAT L4 AND L5

=> ACT LDIELECT2/A

L7 ( 417)SEA FILE=USPAT FLUORINE DOPED  
L8 ( 40475)SEA FILE=USPAT 257/CLAS  
L9 22 SEA FILE=USPAT L7 AND L8

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	2382	(FLUORINE OR FLUORIDE) WITH DOP\$4	USPAT	2000/02/22 08:12
2	BRS	L2	58482	SILICON ADJ (OXIDE OR DIOXIDE)	USPAT	2000/02/22 08:13
3	BRS	L3	12537	TRENCH	USPAT	2000/02/22 08:14
4	BRS	L5	75	1 AND 2 AND 3	USPAT	2000/02/22 09:34
5	BRS	L8	0	1 AND 3 AND 2	EPO; JPO; Derwen t	2000/02/22 09:34

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L2	107	SIOF	USPAT	2000/02/19 08:25
2	BRS	L3	614	FLUORINE ADJ DOP\$4	USPAT	2000/02/19 08:58

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L3	25004	SILICON ADJ OXIDE	USPAT	2000/02/18 16:33
2	BRS	L5	12	2 AND 3	USPAT	2000/02/18 16:35
3	BRS	L8	173	HALIDE ADJ DOP\$4	USPAT	2000/02/18 16:38

	Type	Hits	Search Text
1	BRS	25004	(SILICON ADJ OXIDE)
2	BRS	12	((HALIDE ADJ DOP\$4)) AND ((SILICON ADJ OXIDE)))
3	BRS	173	(HALIDE ADJ DOP\$4)
4	BRS	0	FLORIDE ADJ DOP\$4

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	2382	(FLUORINE OR FLUORIDE) WITH DOP\$4	USPAT	2000/02/22 08:12
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4	BRS	L5	75	1 AND 2 AND 3	USPAT	2000/02/22 08:14